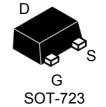


Description

The HCJ3134K uses advanced trench technology to provide excellent $R_{\text{DS}(\text{ON})}$, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a

Battery protection or in other Switching application.



General Features

 $V_{DS} = 20V I_{D} = 1.2A$

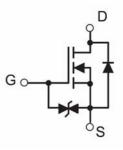
 $R_{DS(ON)}$ < 260 mQ@ V_{GS} = 4.5 V $R_{DS(ON)} < 350 \,\text{m}\Omega$ @ $V_{GS} = 2.5V$ ESD Rating: 1500V HBM

Application

Battery protection

Load switch

Uninterruptible power supply



N-Channel MOSFET

Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
HCJ3134K	SOT-723	KF	8000

Absolute maximum ratings (Ta=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit	
Drain-Source Voltage	V _{DS}	20	V	
Gate-Source Voltage	V _{GS}	±12	V	
Continuous Drain Current	I _D	1.2	А	
Pulsed Drain Current	I _{DM}	1.8	А	
Power Dissipation	P _D	0.15	W	
Thermal Resistance from Junction to Ambient	R _{θJA}	833	°C/W	
Junction Temperature	TJ	150	$^{\circ}$	
Storage Temperature	T _{STG}	-55~ +150	$^{\circ}$ C	

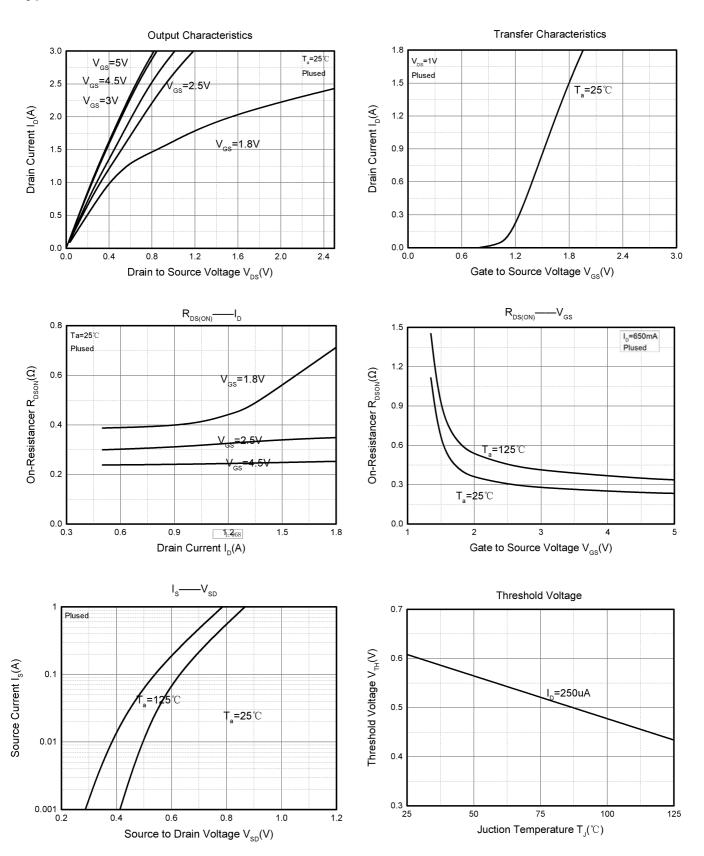


Electrical characteristics (T_A=25 °C, unless otherwise noted)

Parameter	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D =250μA	20			V
Zero gate voltage drain current	I _{DSS}	V _{DS} =16V,V _{GS} = 0V			1	μA
Gate-body leakage current	I _{GSS}	$V_{GS} = \pm 10V$, $V_{DS} = 0V$			±10	uA
Gate threshold voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	0.3	0.65	1	V
	R _{DS(on)}	V _{GS} = 4.5V, I _D = 1.2A		150	260	mΩ
Drain-source on-resistance		V _{GS} =2.5V, I _D = 0.8A		132	168	
		V _{GS} =1.8V, I _D = 0.3A		165	240	
Input Capacitance	C _{iss}			79	120	pF
Output Capacitance	Coss	V _{DS} =16V,V _{GS} =0V, f=1MHz		13	20	
Reverse Transfer Capacitance	C _{rss}	· ······-		9	15	
Turn-on delay time	t _{d(on)}			6.7		
Turn-on rise time	t _r	V _{GS} =4.5V,V _{DS} =10V,		4.8		ns
Turn-off delay time	t _{d(off)}	$I_D = 500 \text{mA}, R_{GEN} = 10\Omega$		17.3		
Turn-off fall time	t _f			7.4		
Body Diode Voltage	V _{SD}	I _S =0.5A, V _{GS} = 0V		0.7	1.3	V

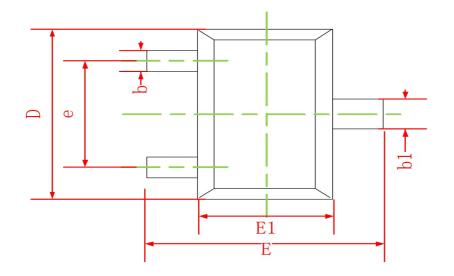


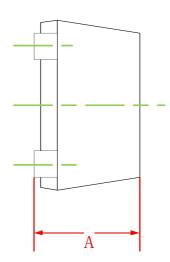
Typical Characteristics

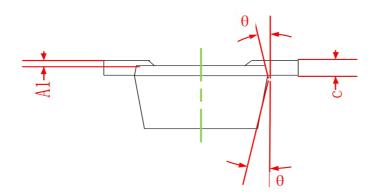




SOT-723 Package Information







Symbol	Dimensions In Millimeters			
	Min.	Max.		
A	0.430	0.500		
A1	0.000	0.050		
b	0.170	0.270		
b1	0.270	0.370		
С	0.080	0.150		
D	1.150	1.250		
E	1.150 1.250			
E1	0.750 0.850			
е	0.800TYP.			
θ	7° REF.			



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DMN1017UCP3-7 EFC2J004NUZTDG P85W28HP2F-7071 DMN1053UCP4-7 NTE2384 DMC2700UDMQ-7 DMN2080UCB4-7
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